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FAIRCHILD

SEMICONDUCTOR

74VCX16501 Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16501 is an 18-bit universal bus transceiver which combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in a highimpedance state.

Data flow for B to A is similar to that of A to B but uses OEBA, LEBA, and CLKBA. The output enables are complementary (OEAB is active HIGH and OEBA is active LOW).

The VCX16501 is designed for low voltage (1.4V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The VCX16501 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.4V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs ■ t_{PD} (A to B, B to A)

2.9 ns max for 3.0V to 3.6V V_{CC}

- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})
- ±24 mA @ 3.0V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model >200V

Note 1: To ensure the high-impedance state during power up or power down, $\overline{\text{OEBA}}$ should be tied to V_{CC} through a pull-up resistor and OEAB should be tied to GND through a pull-down resistor; the minimum value of the resistors is determined by the current-sourcing capability of the driver.

Ordering Code:

Order Number	Package Number	Package Description
74VCX16501MTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
Devices also available	on Tape and Reel. Specify	y by appending the suffix letter "X" to the ordering code.

74VCX16501

Connection Diagram

		· · ·		
0EAB —	1	\bigcirc	56	- GND
LEAB —	2		55	— CLKAB
A ₁ —	3		54	— в ₁
GND —	4		53	- GND
A ₂ —	5		52	— B ₂
A3 —	6		51	— B ₃
v _{cc} —	7		50	– v _{cc}
Α4 —	8		49	— B ₄
A ₅ —	9		48	— B ₅
A ₆ —	10		47	— B ₆
GND —	11		46	- GND
A ₇ —	12		45	— B ₇
A ₈ —	13		44	— в ₈
Ag —	14		43	— в _д
A ₁₀ —	15		42	— B ₁₀
A ₁₁ —	16		41	— B ₁₁
A ₁₂ —	17		40	— B ₁₂
GND —	18		39	- GND
A _{1.3} —	19		38	— В _{1 3}
A ₁₄ —	20		37	— В ₁₄
A ₁₅ —	21		36	— B ₁₅
v _{cc} —	22		35	- v _{cc}
A ₁₆ —	23		34	— В ₁₆
A ₁₇ —	24		33	— В ₁₇
GND —	25		32	- GND
A ₁₈	26		31	— В _{1 8}
OEBA -	27		30	- CLKBA
LEBA —	28		29	- GND
				1

Pin Descriptions

Pin Names	Description
OEAB	Output Enable Input for A to B Direction (Active HIGH)
OEBA	Output Enable Input for B to A Direction (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
A ₁ -A ₁₈	Side A Inputs or 3-STATE Outputs
B ₁ -B ₁₈	Side B Inputs or 3-STATE Outputs

Function Table (Note 2)

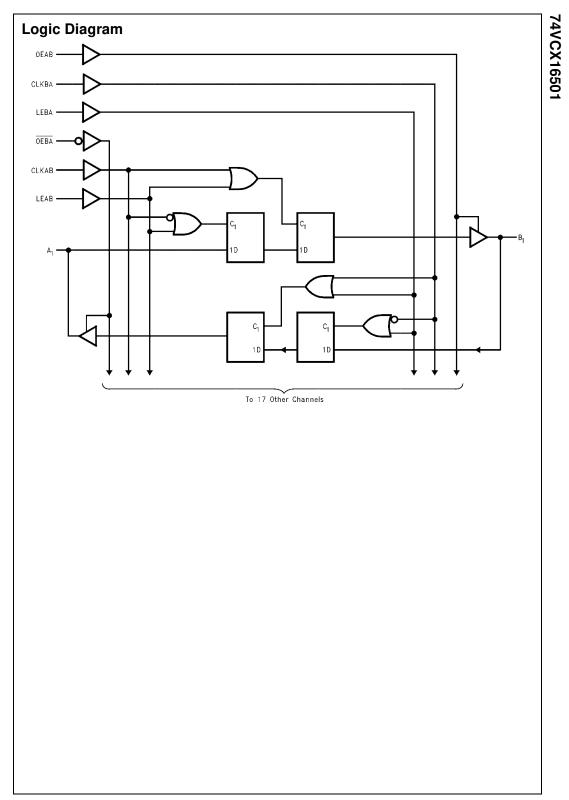
	Inputs			Outputs
OEAB	LEAB	CLKAB	A _n	B _n
L	Х	х	Х	Z
Н	Н	х	L	L
Н	н	х	н	н
Н	L	\uparrow	L	L
Н	L	\uparrow	н	н
Н	L	н	х	B ₀ (Note 3)
н	L	L	Х	B ₀ (Note 4)

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial (HIGH or LOW, inputs may not float) Z = High Impedance

Note 2: A-to-B data flow is shown; B-to-A flow is similar but uses $\overline{\text{OEBA}}$, LEBA and CLKBA. $\overline{\text{OEBA}}$ is active LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.



Absolute Maximum Ratings(Note 5)

		1
Supply Voltage (V _{CC})	-0.5V to +4.6V	C
DC Input Voltage (VI)	-0.5V to +4.6V	
Output Voltage (V _O)		
Outputs 3-STATED	-0.5V to +4.6V	
Outputs Active (Note 6)	–0.5 to V_{CC} + 0.5V	
DC Input Diode Current (I_{IK}) $V_I < 0V$	–50 mA	
DC Output Diode Current (I _{OK})		
V _O < 0V	–50 mA	
$V_{O} > V_{CC}$	+50 mA	
DC Output Source/Sink Current		
(I _{OH} /I _{OL})	±50 mA	
DC V _{CC} or Ground Current per		
Supply Pin (I _{CC} or Ground)	±100 mA	
Storage Temperature Range (T _{STG})	-65°C to +150°C	

Recommended Operating Conditions (Note 7)						
Power Supply						
Operating	1.4V to 3.6V					
Input Voltage	-0.3V to 3.6V					
Output Voltage (V _O)						
Output in Active States	0V to V _{CC}					
Output in 3-STATE	0.0V to 3.6V					
Output Current in I _{OH} /I _{OL}						
$V_{CC} = 3.0V$ to 3.6V	±24 mA					
$V_{CC} = 2.3V$ to 2.7V	±18 mA					
V _{CC} = 1.65V to 2.3V	±6 mA					
$V_{CC} = 1.4V$ to 1.6V	±2 mA					
Free Air Operating Temperature (T _A)	-40°C to +85°C					
Minimum Input Edge Rate ($\Delta t/\Delta V$)						
$V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$	10 ns/V					

Note 5: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 6: I_{O} Absolute Maximum Rating must be observed.

Note 7: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
VIH	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		
			1.65 - 2.3	0.65 x V _{CC}		V
			1.4 - 1.6	0.65 x V _{CC}		
VIL	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	
			1.65 - 2.3		$0.35 \times V_{CC}$	V
			1.4 - 1.6		$0.35 \times V_{CC}$	
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
		I _{OH} = -100 μA	2.3 - 2.7	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.3	2.0		v
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		v
		I _{OH} = -18 mA	2.3	1.7		
		I _{OH} = -100 μA	1.65 - 2.3	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \ \mu A$	1.4 - 1.6	V _{CC} - 0.2		
		$I_{OH} = -12 \text{ mA}$	1.4	1.05		

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2	
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	
		I _{OL} = 18 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
		$I_{OL} = 100 \ \mu A$	2.3 - 2.7		0.2	
		$I_{OL} = 12 \text{ mA}$	2.3		0.4	V
		I _{OL} = 18 mA	2.3		0.6	
		$I_{OL} = 100 \ \mu A$	1.65 - 2.3		0.2	
		$I_{OL} = 6 \text{ mA}$	1.65		0.3	
		$I_{OL} = 100 \ \mu A$	1.4 - 1.6		0.2	
		$I_{OL} = 2 \text{ mA}$	1.4		0.35	
1	Input Leakage Current	$0V \le V_1 \le 3.6V$	1.4 - 3.6		±5.0	μA
oz	3-STATE Output Leakage	$0V \le V_O \le 3.6V$	1.4 - 3.6		±10.0	
		$V_I = V_{IH}$ or V_{IL}	1.4 - 3.6		±10.0	μA
OFF	Power Off Leakage Current	$0V \le (V_I, V_O) \le 3.6V$	0		10.0	μA
сс	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.4 - 3.6		20.0	
		$V_{CC} \leq (V_I, V_O) \leq 3.6V \text{ (Note 8)}$	1.4 - 3.6		±20.0	μA
۵ا _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μA

Note 8: Outputs disabled or 3-STATE only.

Symbol	Demonstern	O an dition o	V _{CC}			11 24	Fi		
Symbol	Parameter	Conditions	(V)	Min	Max	Units	Nu		
f _{MAX}	Maximum Clock Frequency	$C_L = 30 \text{ pF}$	3.3 ± 0.3	250					
			2.5 ± 0.2	200		MHz			
			1.8 ± 0.15	100		IVII 12			
		$C_L = 15 \text{ pF}$	1.5 ± 0.1	80.0					
t _{PHL}	Propagation Delay	$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	3.3 ± 0.3	0.6	2.9				
t _{PLH}			2.5 ± 0.2	0.8	3.5		Fi		
			1.8 ± 0.15	1.5	7.0	ns			
		$C_L = 15 \text{ pF}, \text{ R}_L = 2k\Omega$	1.5 ± 0.1	1.0	14.0		Fi		
t _{PHL}	Propagation Delay	$C_L = 15 \text{ pF}, \text{ R}_L = 500 \Omega$	3.3 ± 0.3	0.6	3.5		-		
t _{PLH}	Clock-to-Bus		2.5 ± 0.2	0.8	4.4		Fi		
			1.8 ± 0.15	1.5	8.8	ns			
		$C_L = 15 \text{ pF}, \text{ R}_L = 500 \Omega$	1.5 ± 0.1	1.0	17.6		Fi		
t _{PHL}	Propagation Delay	$C_{L} = 30 \text{ pF}, R_{L} = 500 \Omega$	3.3 ± 0.3	0.6	3.8				
t _{PLH}	LE-to-Bus		2.5 ± 0.2	0.8	4.9	ns	Fi		
			1.8 ± 0.15	1.5	9.8				
		$C_L = 15 \text{ pF}, \text{ R}_L = 500 \Omega$	1.5 ± 0.1	1.0	19.6		Fi		
t _{PZL}	Output Enable Time	$C_{L} = 30 \text{ pF}, R_{L} = 500 \Omega$	3.3 ± 0.3	0.6	3.8	ns			
t _{PZH}			2.5 ± 0.2	0.8	4.9		Fi 1		
			1.8 ± 0.15	1.5	9.8				
		$C_L = 15 \text{ pF}, \text{ R}_L = 2k\Omega$	1.5 ± 0.1	1.0	19.6		Fi 7,		
t _{PLZ}	Output Disable Time	$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	3.3 ± 0.3	0.8	3.7			_	
t _{PHZ}			2.5 ± 0.2	0.8	4.2		Fi 1		
			1.8 ± 0.15	0.8	7.6	ns			
		$C_L = 15 \text{ pF}, \text{ R}_L = 2k\Omega$	1.5 ± 0.1	1.0	15.2		Fi 7,		
t _S	Setup Time	$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	3.3 ± 0.3	1.5			_		
			2.5 ± 0.2	1.5			Fi		
			1.8 ± 0.15	2.5		ns			
		$C_L = 15 \text{ pF}, \text{ R}_L = 500 \Omega$	1.5 ± 0.1	3.0			Fi		
t _H	Hold Time	$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	3.3 ± 0.3	1.0			1_		
			2.5 ± 0.2	1.0			Fi		
			1.8 ± 0.15	1.0		ns			
		$C_L = 15 \text{ pF}, \text{ R}_L = 500 \Omega$	1.5 ± 0.1	2.0			Fi		
tw	Pulse Width	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	1.5					
		_	2.5 ± 0.2	1.5			Fi		
			1.8 ± 0.15	4.0		ns			
		$C_L = 15 \text{ pF}, \text{ R}_L = 500 \Omega$	1.5 ± 0.1	4.0			Fi		
t _{OSHL}	Output-to-Output Skew	$C_{L} = 30 \text{ pF}, \text{ R}_{L} = 500 \Omega$	3.3 ± 0.3		0.5				
tOSLH	(Note 10)		2.5 ± 0.2		0.5				
			1.8 ± 0.15		0.75	ns			
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5				

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Symbol	Parameter	Conditions	V _{cc}	$T_A = +25^{\circ}C$	Units
Symbol	i arameter		(V)	Typical	onito
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units
C _{IN}	Input Capacitance	V_{CC} = 1.8V, 2.5V, or 3.3V, V_I = 0V or V_{CC}	6.0	pF
C _{I/O}	Output Capacitance	$V_I = 0V$, or V_{CC} , $V_{CC} = 1.8V$, 2.5V or 3.3V	7.0	pF
CPD	Power Dissipation Capacitance	V_{I} = 0V or V_{CC},f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20.0	pF

